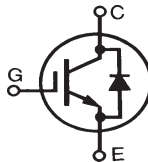


## High Speed IGBT

**IXSA 20N60B2D1**  
**IXSP 20N60B2D1**

Short Circuit SOA Capability

Preliminary Data Sheet



$$V_{CES} = 600 \text{ V}$$

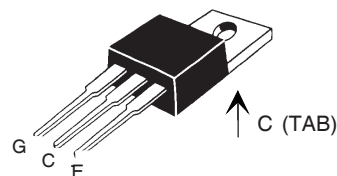
$$I_{C25} = 35 \text{ A}$$

$$V_{CE(sat)} = 2.5 \text{ V}$$

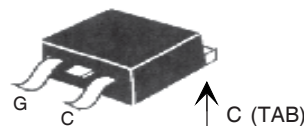
| Symbol  | Test Conditions  | Maximum Ratings                  |                  |
|---|--|----------------------------------|------------------|
| $V_{CES}$   | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$  | 600                              | V                |
| $V_{CGR}$   | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ ; $R_{GE} = 1 \text{ M}\Omega$                                       | 600                              | V                |
| $V_{GES}$   | Continuous   | $\pm 20$                         | V                |
| $V_{GEM}$   | Transient  | $\pm 30$                         | V                |
| $I_{C25}$   | $T_C = 25^\circ\text{C}$   | 35                               | A                |
| $I_{C110}$  | $T_C = 110^\circ\text{C}$  | 20                               | A                |
| $I_{F(110)}$  |  | 11                               | A                |
| $I_{CM}$  | $T_C = 25^\circ\text{C}$ , 1 ms  | 60                               | A                |
| <b>SSOA (RBSOA)</b>   | $V_{GE} = 15 \text{ V}$ , $T_J = 125^\circ\text{C}$ , $R_G = 82 \Omega$<br>Clamped inductive load                    | $I_{CM} = 32$<br>@ $0.8 V_{CES}$ | A                |
| <b><math>t_{SC}</math> (SCSOA)</b>  | $V_{GE} = 15 \text{ V}$ , $V_{CE} = 360 \text{ V}$ , $T_J = 125^\circ\text{C}$<br>$R_G = 82 \Omega$ , non repetitive | 10                               | $\mu\text{s}$    |
| $P_C$   | $T_C = 25^\circ\text{C}$   | 190                              | W                |
| $T_J$   |  | -55 ... +150                     | $^\circ\text{C}$ |
| $T_{JM}$  |  | 150                              | $^\circ\text{C}$ |
| $T_{stg}$   |  | -55 ... +150                     | $^\circ\text{C}$ |
| <b>Weight</b>   |  | 2                                | g                |
| Maximum lead temperature for soldering<br>1.6 mm (0.062 in.) from case for 10 s |  | 300                              | $^\circ\text{C}$ |
| Maximum tab temperature for soldering for 10s                                   |  | 260                              | $^\circ\text{C}$ |

| Symbol        | Test Conditions   | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                            |
|---------------|---|---|------|----------------------------|
|               |   | min.  | typ. | max.                       |
| $BV_{CES}$    | $I_C = 250 \mu\text{A}$ , $V_{GE} = 0 \text{ V}$                          | 600   |      | V                          |
| $V_{GE(th)}$  | $I_C = 750 \mu\text{A}$ , $V_{CE} = V_{GE}$                               | 3.5   |      | 6.5 V                      |
| $I_{CES}$     | $V_{CE} = V_{CES}$<br>$V_{GE} = 0 \text{ V}$<br>$T_J = 125^\circ\text{C}$ |   |      | 85 $\mu\text{A}$<br>0.6 mA |
| $I_{GES}$     | $V_{CE} = 0 \text{ V}$ , $V_{GE} = \pm 20 \text{ V}$                      |   |      | $\pm 100 \text{ nA}$       |
| $V_{CE(sat)}$ | $I_C = 16 \text{ A}$ , $V_{GE} = 15 \text{ V}$                            |   |      | 2.5 V                      |

TO-220 (IXSP)



TO-220 (IXSA)



G = Gate      C = Collector  
E = Emitter    TAB = Collector

### Features

- International standard packages
- Guaranteed Short Circuit SOA capability
- Low  $V_{CE(sat)}$ 
  - for low on-state conduction losses
- High current handling capability
- MOS Gate turn-on
  - drive simplicity
- Fast fall time for switching speeds up to 20 kHz

### Applications

- AC motor speed control
- Uninterruptible power supplies (UPS)
- Welding

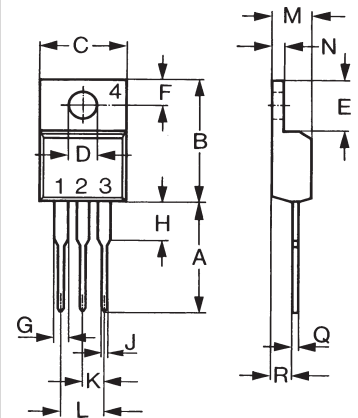
### Advantages

- High power density

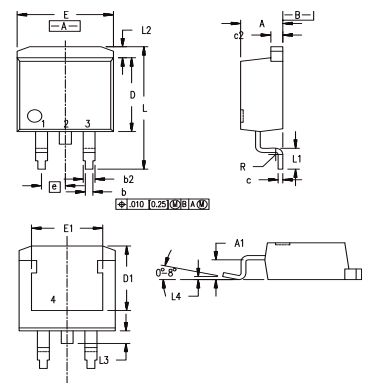
| Symbol       | Test Conditions   | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                   |
|--------------|---|---|------|-------------------|
|              |   | min.  | typ. | max.              |
| $g_{fs}$     | $I_C = 16\text{A}; V_{CE} = 10\text{V}$ , Note 1  | 3.5   | 7.0  | S                 |
| $C_{ies}$    | $V_{CE} = 25\text{V}, V_{GE} = 0\text{V}$<br>$f = 1\text{MHz}$<br>20N60B2D1                                     |   | 800  | pF                |
| $C_{oes}$    |   |   | 76   | pF                |
| $C_{res}$    |   |   | 90   | pF                |
| $Q_g$        |   |   | 28   | pF                |
| $Q_{ge}$     | $I_C = 16\text{A}, V_{GE} = 15\text{V}, V_{CE} = 0.5 V_{CES}$   |   | 33   | nC                |
| $Q_{gc}$     |   |   | 12   | nC                |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b>  |   | 30   | ns                |
| $t_{ri}$     | $I_C = 16\text{A}, V_{GE} = 15\text{V}$<br>$V_{CE} = 0.8 V_{CES}, R_G = 10\ \Omega$                             |   | 30   | ns                |
| $t_{d(off)}$ | Switching times may increase for $V_{CE}$<br>(Clamp) $> 0.8 \cdot V_{CES}$ , higher $T_J$ or<br>increased $R_G$ |   | 116  | ns                |
| $t_{fi}$     |   |   | 126  | ns                |
| $E_{off}$    |   |   | 380  | 600 $\mu\text{J}$ |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 125^\circ\text{C}</math></b>   |   | 30   | ns                |
| $t_{ri}$     |   |   | 30   | ns                |
| $E_{on}$     | $I_C = 16\text{A}, V_{GE} = 15\text{V}$<br>$V_{CE} = 0.8 V_{CES}, R_G = 10\ \Omega$<br>20N60B2<br>20N60B2D1     |   | 0.12 | mJ                |
| $t_{d(off)}$ | Switching times may increase for<br>$V_{CE}$ (Clamp) $> 0.8 \cdot V_{CES}$ , higher $T_J$<br>or increased $R_G$ |   | 0.42 | mJ                |
| $t_{fi}$     |   |   | 180  | ns                |
| $t_{fi}$     |   |   | 210  | ns                |
| $E_{off}$    |   |   | 970  | $\mu\text{J}$     |
| $R_{thJC}$   |   |   |      | 0.66 K/W          |
| $R_{thCS}$   |   |   | 0.3  | K/W               |

| Symbol     | Test Conditions   | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                  |
|------------|---|---|------|------------------|
|            |   | min.  | typ. | max.             |
| $V_F$      | $I_F = 10\text{A}, V_{GE} = 0\text{V}$<br>$T_J = 150^\circ\text{C}$                                     |   |      | 1.66 V<br>2.66 V |
| $I_{RM}$   | $I_F = 12\text{A}, V_{GE} = 0\text{V}, -di_F/dt = 100\text{A}/\mu\text{s}$<br>$T_J = 100^\circ\text{C}$ |   | 1.5  | A                |
| $t_{rr}$   | $V_R = 100\text{V}$<br>$T_J = 100^\circ\text{C}$  |   | 90   | ns               |
| $t_{rr}$   | $I_F = 1\text{A}; -di/dt = 100\text{A}/\mu\text{s}; V_R = 30\text{V}$                                   |   | 30   | ns               |
| $R_{thJC}$ |   |   |      | 2.5 K/W          |

Note 1: Pulse test,  $t \leq 300\ \mu\text{s}$ , duty cycle  $d \leq 2\%$

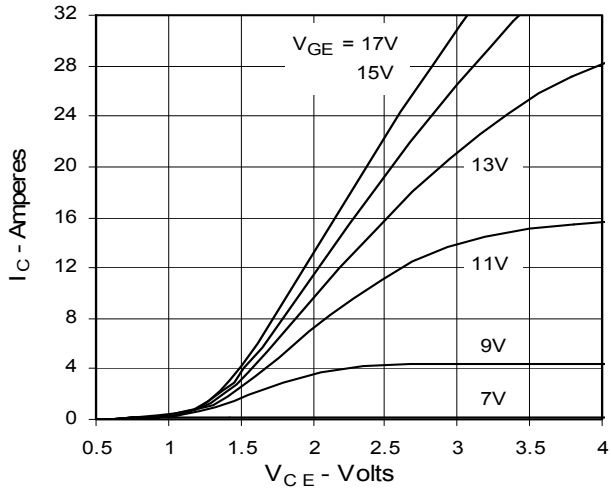
**TO-220 AB (IXSP) Outline**


| Dim. | Millimeter |       | Inches |       |
|------|------------|-------|--------|-------|
|      | Min.       | Max.  | Min.   | Max.  |
| A    | 12.70      | 13.97 | 0.500  | 0.550 |
| B    | 14.73      | 16.00 | 0.580  | 0.630 |
| C    | 9.91       | 10.66 | 0.390  | 0.420 |
| D    | 3.54       | 4.08  | 0.139  | 0.161 |
| E    | 5.85       | 6.85  | 0.230  | 0.270 |
| F    | 2.54       | 3.18  | 0.100  | 0.125 |
| G    | 1.15       | 1.65  | 0.045  | 0.065 |
| H    | 2.79       | 5.84  | 0.110  | 0.230 |
| J    | 0.64       | 1.01  | 0.025  | 0.040 |
| K    | 2.54       | BSC   | 0.100  | BSC   |
| M    | 4.32       | 4.82  | 0.170  | 0.190 |
| N    | 1.14       | 1.39  | 0.045  | 0.055 |
| Q    | 0.35       | 0.56  | 0.014  | 0.022 |
| R    | 2.29       | 2.79  | 0.090  | 0.110 |

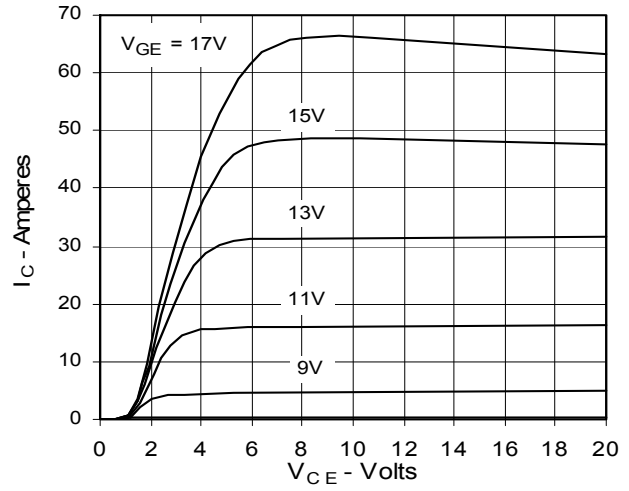
**TO-263 (IXSA) Outline**


| Dim. | Millimeter |       | Inches |      |
|------|------------|-------|--------|------|
|      | Min.       | Max.  | Min.   | Max. |
| A    | 4.06       | 4.83  | .160   | .190 |
| A1   | 2.03       | 2.79  | .080   | .110 |
| b    | 0.51       | 0.99  | .020   | .039 |
| b2   | 1.14       | 1.40  | .045   | .055 |
| c    | 0.46       | 0.74  | .018   | .029 |
| c2   | 1.14       | 1.40  | .045   | .055 |
| D    | 8.64       | 9.65  | .340   | .380 |
| D1   | 7.11       | 8.13  | .280   | .320 |
| E    | 9.65       | 10.29 | .380   | .405 |
| E1   | 6.86       | 8.13  | .270   | .320 |
| e    | 2.54       | BSC   | .100   | BSC  |
| L    | 14.61      | 15.88 | .575   | .625 |
| L1   | 2.29       | 2.79  | .090   | .110 |
| L2   | 1.02       | 1.40  | .040   | .055 |
| L3   | 1.27       | 1.78  | .050   | .070 |
| L4   | 0          | 0.38  | 0      | .015 |
| R    | 0.46       | 0.74  | .018   | .029 |

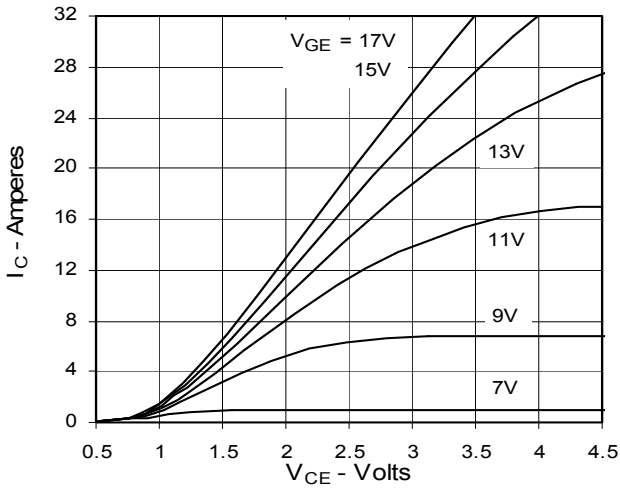
**Fig. 1. Output Characteristics @ 25 °C**



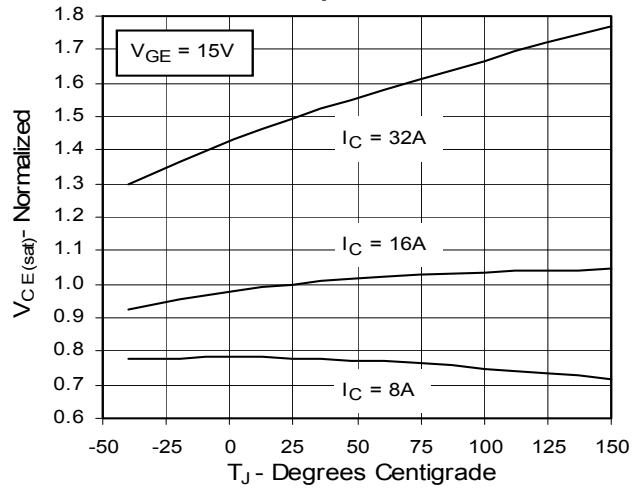
**Fig. 2. Extended Output Characteristics @ 25 °C**



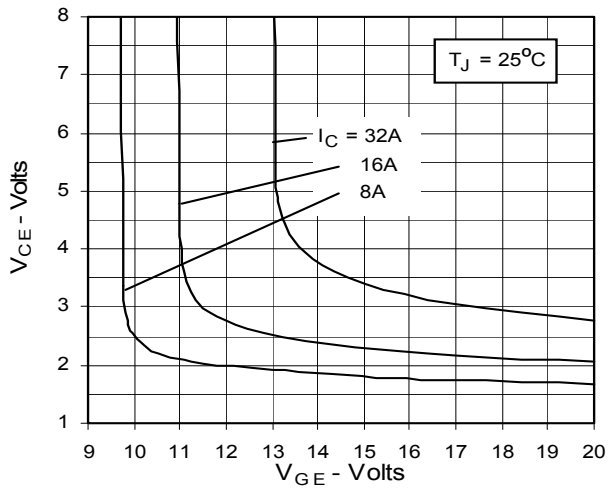
**Fig. 3. Output Characteristics @ 125 °C**



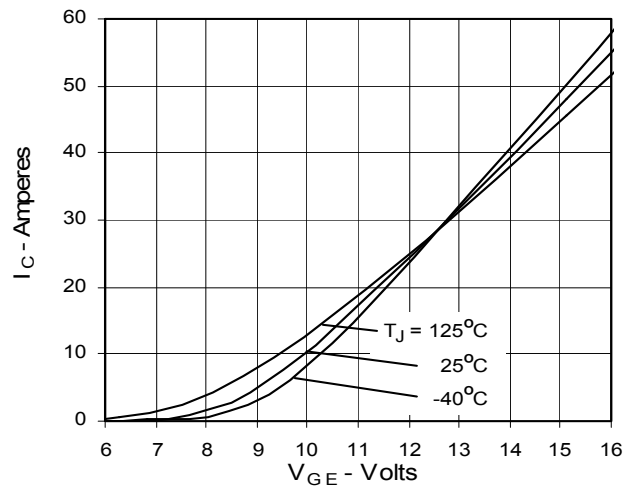
**Fig. 4. Dependence of  $V_{CE(sat)}$  on Temperature**



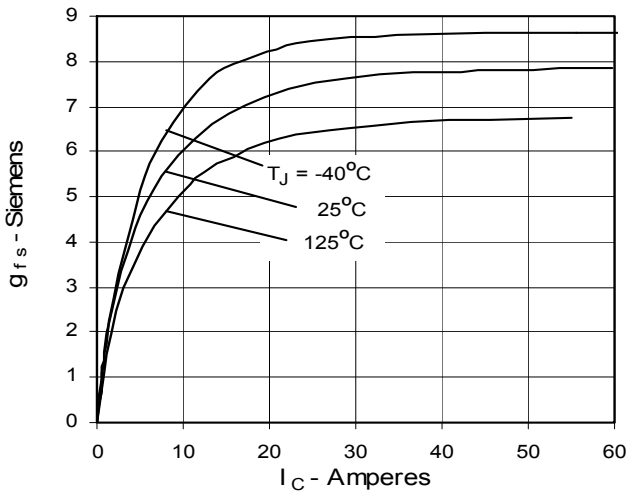
**Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter voltage**



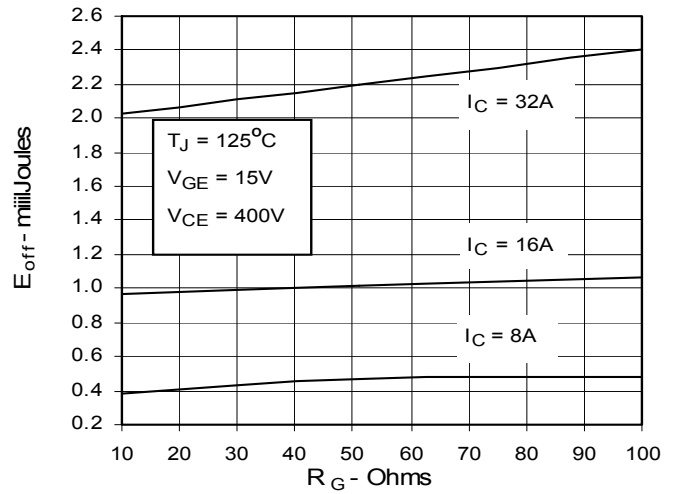
**Fig. 6. Input Admittance**



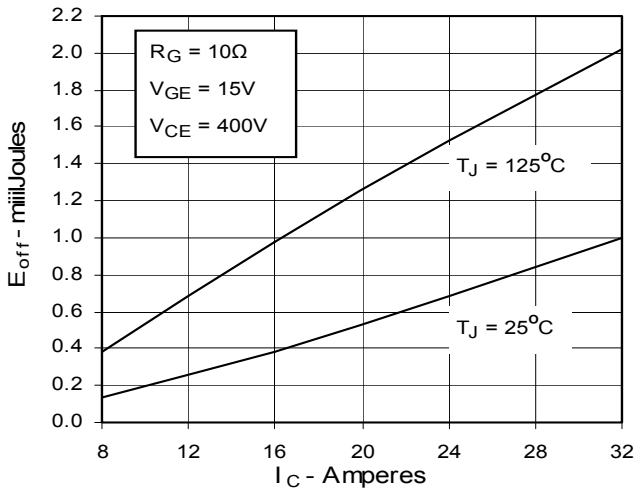
**Fig. 7. Transconductance**



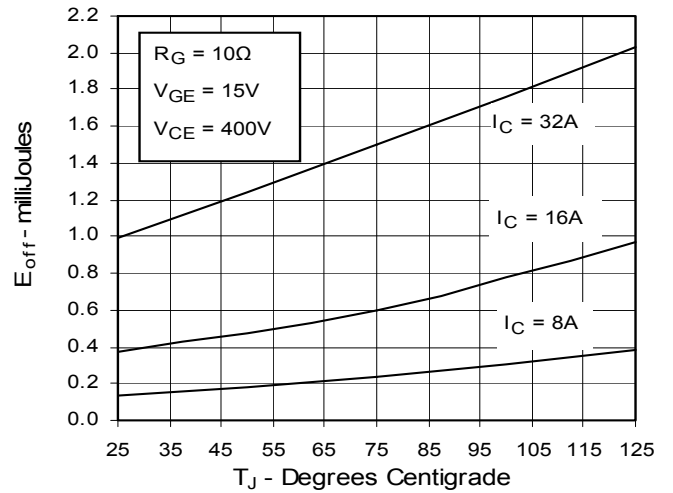
**Fig. 8. Dependence of Turn-off Energy Loss on  $R_G$**



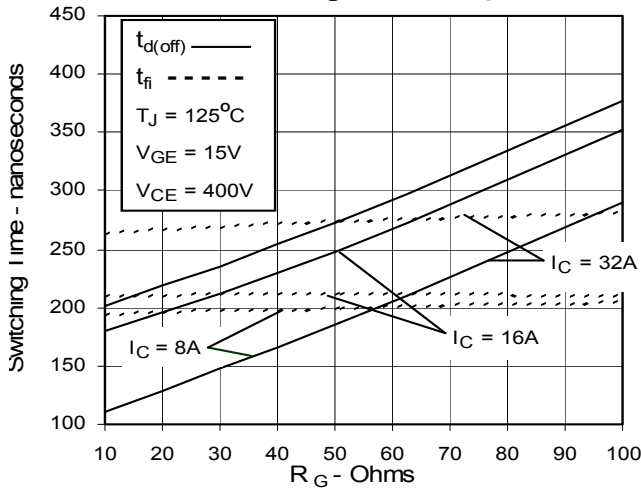
**Fig. 9. Dependence of Turn-Off Energy Loss on  $I_C$**



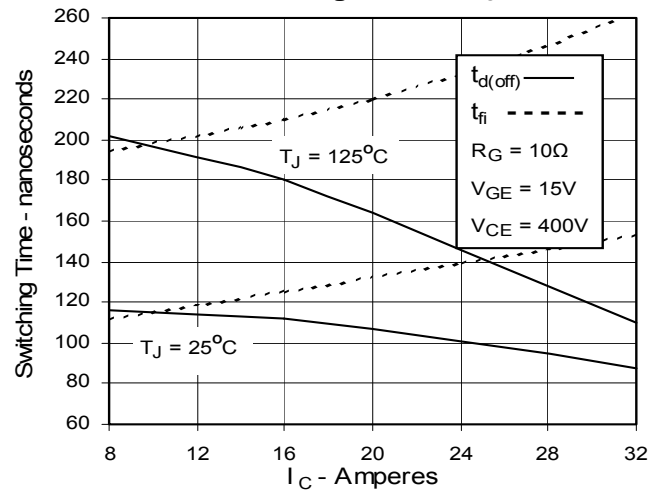
**Fig. 10. Dependence of Turn-off Energy Loss on Temperature**



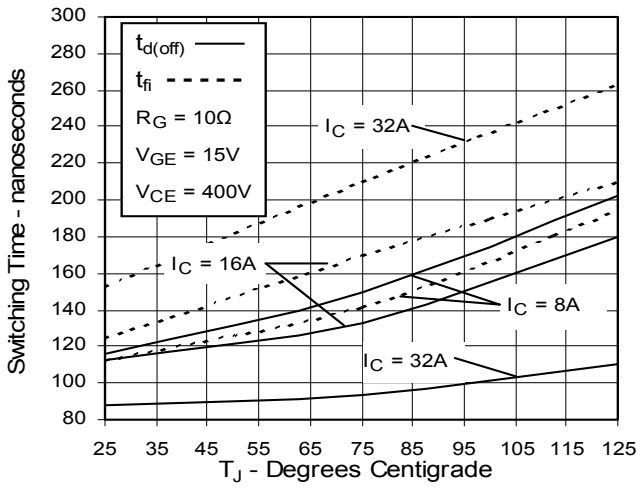
**Fig. 11. Dependence of Turn-off Switching Time on  $R_G$**



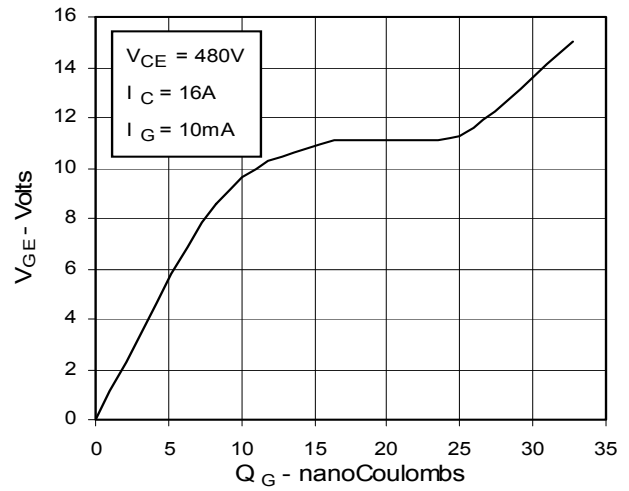
**Fig. 12. Dependence of Turn-off Switching Time on  $I_C$**



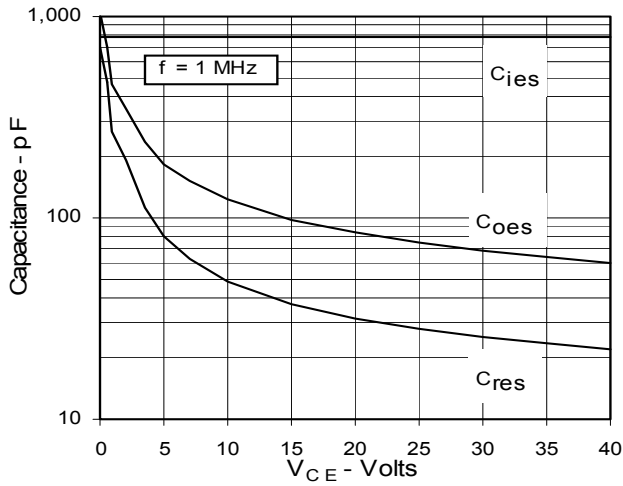
**Fig. 13. Dependence of Turn-off Switching Time on Temperature**



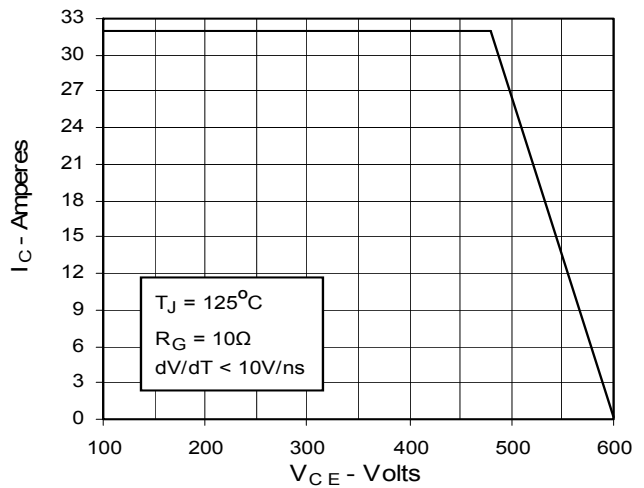
**Fig. 14. Gate Charge**



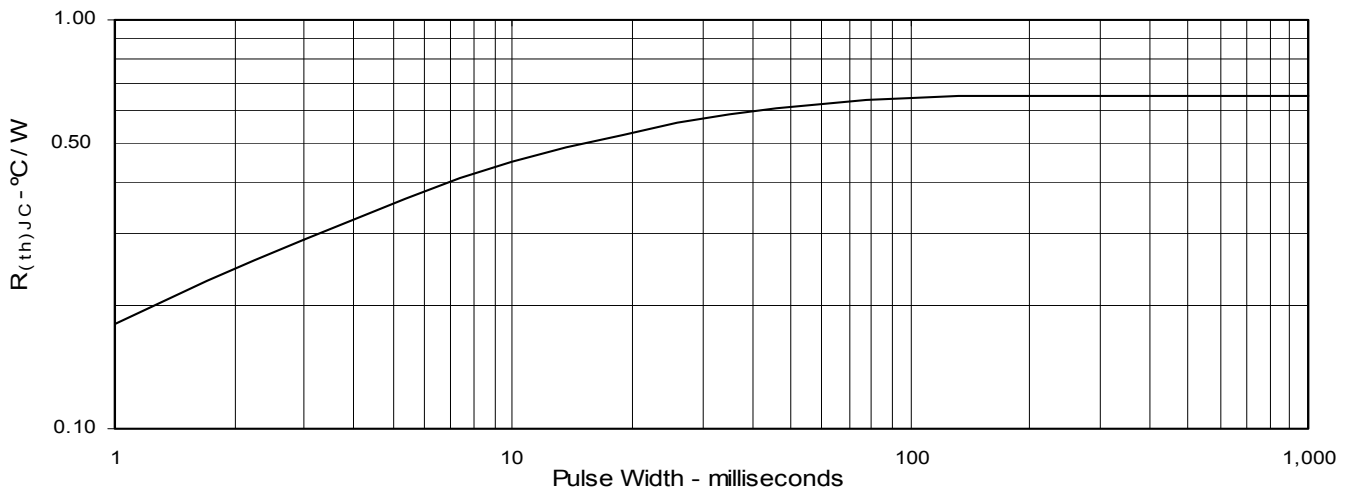
**Fig. 15. Capacitance**



**Fig. 16. Reverse-Bias Safe Operating Area**



**Fig. 17. Maximum Transient Thermal Resistance**



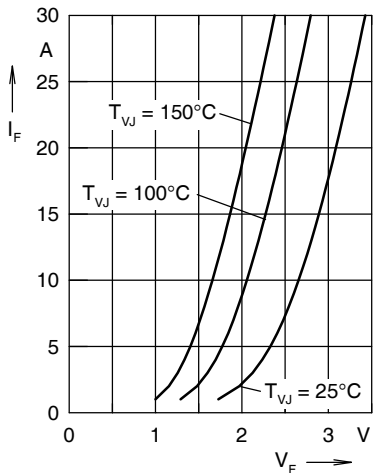


Fig. 18. Forward current  $I_F$  versus  $V_F$

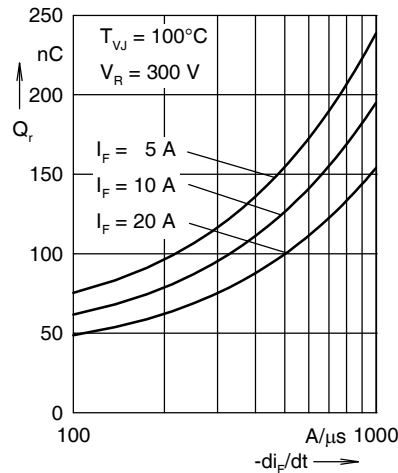


Fig. 19. Reverse recovery charge  $Q_r$

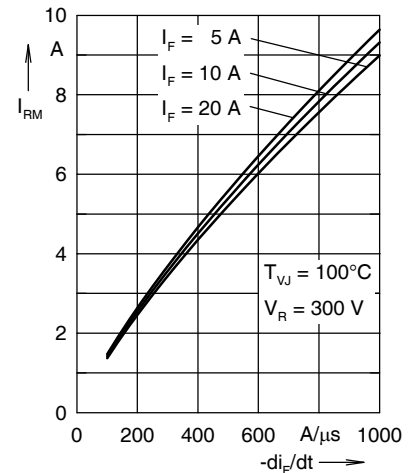


Fig. 20. Peak reverse current  $I_{RM}$

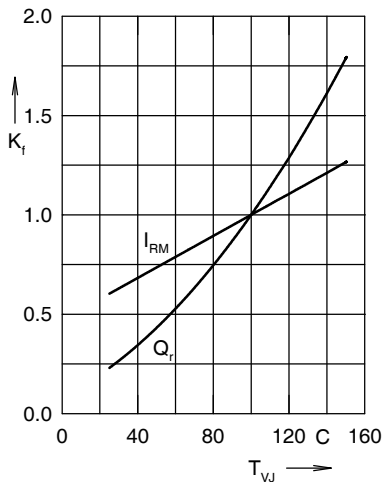


Fig. 21. Dynamic parameters  $Q_r$ ,  $I_{RM}$

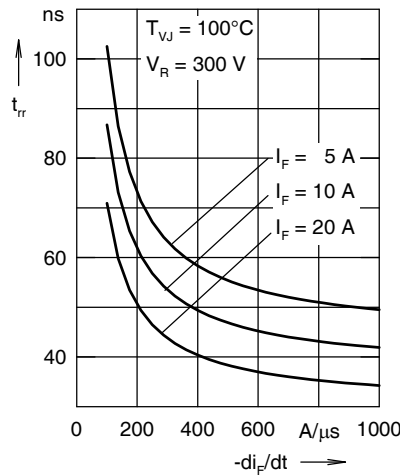


Fig. 22. Recovery time  $t_{tr}$  versus  $-di_F/dt$

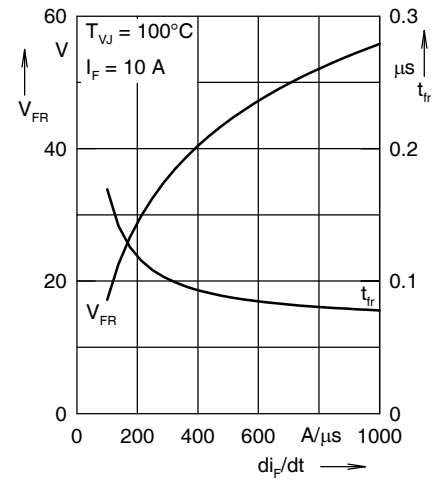


Fig. 23. Peak forward voltage  $V_{FR}$  and  $t_{tr}$

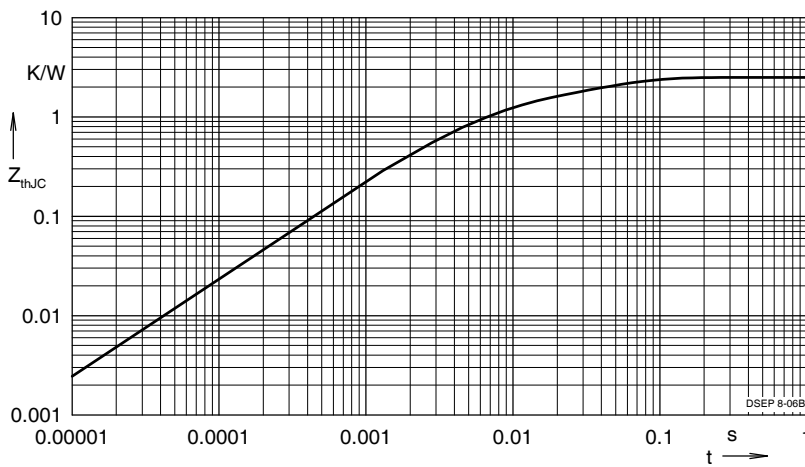


Fig. 24. Transient thermal resistance junction-to-case

Constants for  $Z_{thJC}$  calculation:

| i | $R_{thi}$ (K/W) | $t_i$ (s) |
|---|-----------------|-----------|
| 1 | 1.449           | 0.0052    |
| 2 | 0.5578          | 0.0003    |

NOTE: Fig. 18 to Fig. 23 shows typical values

IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

|           |           |           |           |           |           |              |              |           |              |
|-----------|-----------|-----------|-----------|-----------|-----------|--------------|--------------|-----------|--------------|
| 4,835,592 | 4,881,106 | 5,017,508 | 5,049,961 | 5,187,117 | 5,381,025 | 6,162,665    | 6,306,728 B1 | 6,534,343 | 6,683,344    |
| 4,850,072 | 4,931,844 | 5,034,796 | 5,063,307 | 5,237,481 | 5,486,715 | 6,259,123 B1 | 6,404,065 B1 | 6,583,505 | 6,710,405 B2 |